



ELECTRONICS, INC.
 44 FARRAND STREET
 BLOOMFIELD, NJ 07003
 (973) 748-5089
<http://www.nteinc.com>

NTE6111 & NTE6114 Silicon Power Rectifier Diode, 1100 Amp

Features:

- Wide Current Range
- High Voltage Rating
- High Surge Current Capabilities

Applications:

- Converters
- Power Supplies
- Machine Tool Controls
- High Power Drives
- Medium Traction Applications

Absolute Maximum Ratings:

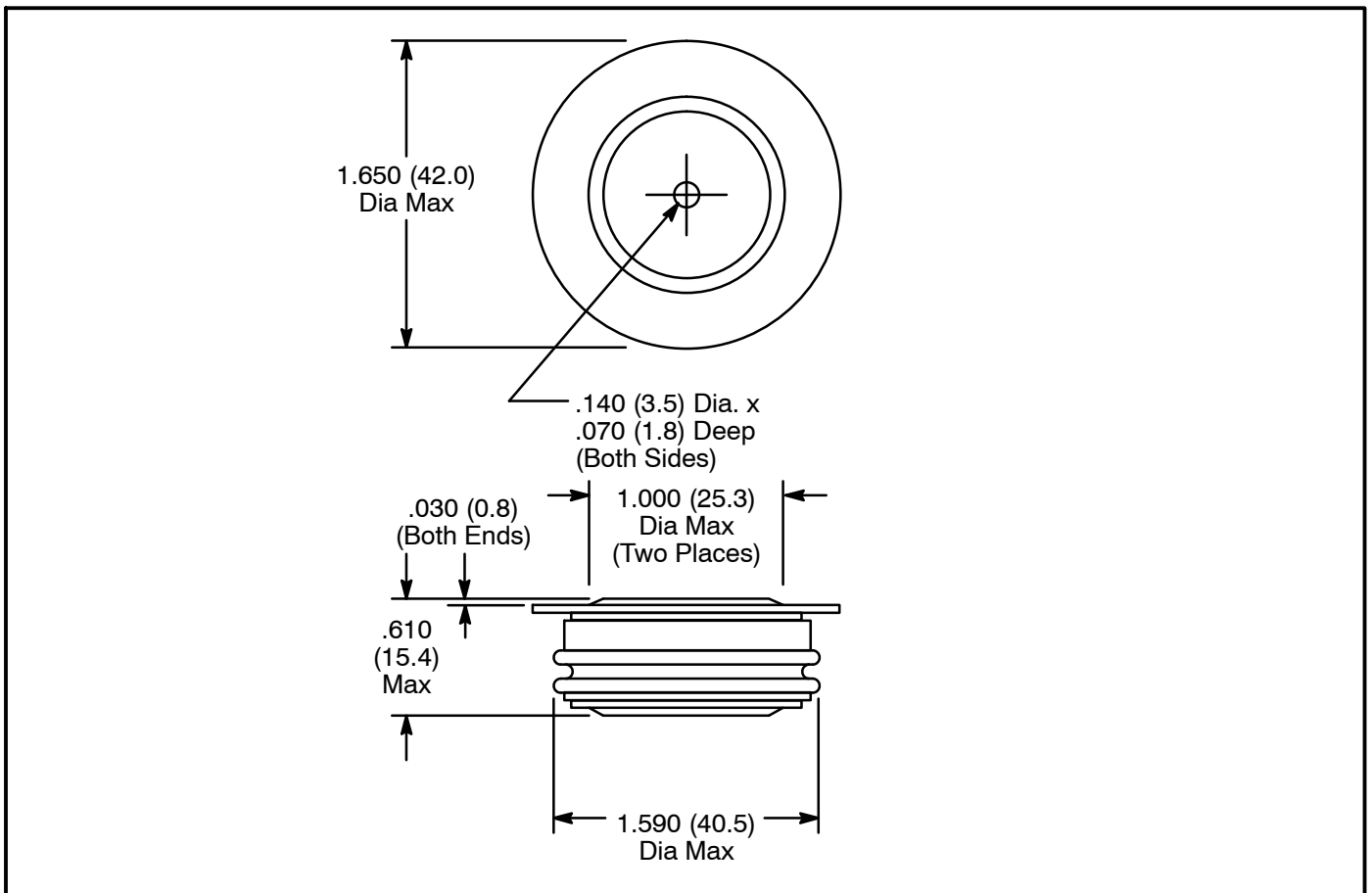
Maximum Repetitive Peak Reverse Voltage, V_{RRM}	
NTE6111	600V
NTE6114	1600V
Maximum Non-Repetitive Peak Reverse Voltage, V_{RSM}	
NTE6111	700V
NTE6114	1700V
Maximum Reverse Current ($T_J = +180^\circ\text{C}$), I_{RRM}	
15mA	
Operating Junction Temperature Range, T_J	
-40° to +180°C	
Storage Temperature Range, T_{stg}	
-55° to +200°C	
Maximum Thermal Resistance, Junction-to-Heatsink (DC Operation), $R_{th(j-hs)}$	
Single Side Cooled	0.076°C/W
Double Side Cooled	0.038°C/W
Maximum Mounting Force ($\pm 10\%$), F	
9800 (1000) N (Kg)	

Electrical Specifications:

Parameter	Symbol	Test Conditions	Rating	Unit
Maximum Average Forward Current	$I_F (AV)$	180° condition, Half sine wave	1400	A
		Double side cooled, $T_C = +55^\circ\text{C}$	795	A
		Single side cooled, $T_C = +85^\circ\text{C}$		

Electrical Specifications (Cont'd):

Parameter	Symbol	Test Conditions		Rating	Unit
Maximum RMS Forward Current	$I_{F(RMS)}$	@ +25°C heatsink temperature double side cooled		2500	A
Maximum Peak One-Cycle Forward Non-Repetitive Surge Current	I_{FSM}	t = 10ms	Sinusoidal Halfwave, 100% V_{RRM} Reapplied, Initial $T_J = +180^\circ\text{C}$	10930	A
		t = 8.3ms		11450	A
		t = 10ms	Sinusoidal Halfwave, No Voltage Reapplied, Initial $T_J = +180^\circ\text{C}$	13000	A
		t = 8.3ms		13600	A
Maximum I^2t for Fusing	I^2t	t = 10ms	Sinusoidal Halfwave, 100% V_{RRM} Reapplied, Initial $T_J = +180^\circ\text{C}$	598	A^2s
		t = 8.3ms		546	A^2s
		t = 10ms	Sinusoidal Halfwave, No Voltage Reapplied, Initial $T_J = +180^\circ\text{C}$	846	A^2s
		t = 8.3ms		772	A^2s
Maximum $I^2\sqrt{t}$ for Fusing	$I^2\sqrt{t}$	t = 0.1 to 10ms, no voltage reapplied		8460	$\text{A}^2\sqrt{\text{t}}$
Threshold Voltage, Low Level	$V_{F(TO)1}$	$T_J = +180^\circ\text{C}$, $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$		0.78	V
Threshold Voltage, High Level	$V_{F(TO)2}$	$T_J = +180^\circ\text{C}$, $(I > \pi \times I_{F(AV)})$		0.94	V
Forward Slope Resistance, Low Level	r_{f1}	$T_J = +180^\circ\text{C}$, $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$		0.35	$\text{m}\Omega$
Forward Slope Resistance, High Level	r_{f2}	$T_J = +180^\circ\text{C}$, $(I > \pi \times I_{F(AV)})$		0.26	$\text{m}\Omega$
Maximum Forward Voltage Drop	V_{FM}	$T_J = +180^\circ\text{C}$, $I_{pk} = 1500\text{A}$, $t_p = 10\text{ms}$		1.31	V



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [nte manufacturer](#):

Other Similar products are found below :

[747](#) [797](#) [868](#) [1724](#) [NEH680M50FE](#) [NEHH1.0M450CB](#) [NTE48](#) [NTE526A](#) [228A](#) [231](#) [954](#) [2023](#) [47-20848-R](#) [510](#) [R04-11A30-120](#) [04-SLPE3750A](#) [5615](#) [591](#) [7056](#) [NTE5710](#) [7448](#) [NEH.10M50AA](#) [NEH2.2M63AA](#) [NEH330M35DD](#) [NEH33M10AA](#) [NEV.22M100AA](#) [TP0006-100](#) [NTE182](#) [NTE528](#) [NTE542](#) [NTE74154](#) [WH20-02-25](#) [04-SCBW25L-BK](#) [04-SCBW32L-BK](#) [04-SCW10C-BK](#) [04-SCBW19L-GR](#) [04-SCW19L-WH](#) [04-SCW19L-OR](#) [04-SCW38L-WH](#) [04-SCBW50L-OR](#) [04-SCBW50L-GR](#) [04-SCW10C-GR](#) [04-SCW10C-OR](#) [04-SCBW32L-GR](#) [04-SCBW32L-WH](#) [04-SCBW32L-OR](#) [04-SCBW6C-WH](#) [04-SCBW6C-GR](#) [04-SCBW6C-OR](#) [04-SCBW25L-GR](#)